



SamHop Microelectronics Corp.



STT626

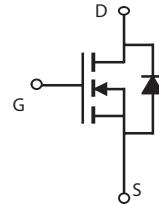
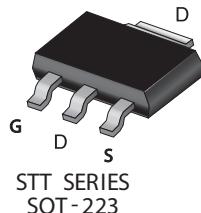
Ver 1.0

N-Channel Logic Level Enhancement Mode Field Effect Transistor

PRODUCT SUMMARY		
VDSS	ID	RDS(ON) (mΩ) Max
60V	8A	27 @ VGS=10V

FEATURES

- Super high dense cell design for low RDS(ON).
- Rugged and reliable.
- Surface Mount Package.



ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Limit	Units
V_{DS}	Drain-Source Voltage	60	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous ^{a,e}	8	A
	$T_C=25^\circ\text{C}$	8	A
	$T_C=70^\circ\text{C}$	6.4	A
I_{DM}	-Pulsed ^b	53	A
E_{AS}	Single Pulse Avalanche Energy ^d	72	mJ
P_D	Maximum Power Dissipation ^a	3	W
	$T_C=25^\circ\text{C}$	3	W
	$T_C=70^\circ\text{C}$	1.9	W
T_J, T_{STG}	Operating Junction and Storage Temperature Range	-55 to 150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient ^a	42	$^\circ\text{C/W}$
-----------------	--	----	--------------------

STT626

Ver 1.0

ELECTRICAL CHARACTERISTICS ($T_A=25^\circ C$ unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
OFF CHARACTERISTICS						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	60			V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =48V , V _{GS} =0V			1	uA
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±20V , V _{DS} =0V			±100	nA
ON CHARACTERISTICS						
V _{G(S(th))}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250uA	2	2.6	4	V
R _{D(S(ON))}	Drain-Source On-State Resistance	V _{GS} =10V , I _D =4A		21	27	m ohm
g _{FS}	Forward Transconductance	V _{DS} =10V , I _D =4A		11		S
DYNAMIC CHARACTERISTICS ^c						
C _{ISS}	Input Capacitance	V _{DS} =25V, V _{GS} =0V f=1.0MHz		2300		pF
C _{OSS}	Output Capacitance			143		pF
C _{RSS}	Reverse Transfer Capacitance			105		pF
SWITCHING CHARACTERISTICS ^c						
t _{D(ON)}	Turn-On Delay Time	V _{DD} =30V I _D =1A V _{GS} =10V R _{GEN} = 6 ohm		50		ns
t _r	Rise Time			30		ns
t _{D(OFF)}	Turn-Off Delay Time			61		ns
t _f	Fall Time			12		ns
Q _g	Total Gate Charge	V _{DS} =30V, I _D =4A, V _{GS} =10V		25		nC
Q _{gs}	Gate-Source Charge	V _{DS} =30V, I _D =4A, V _{GS} =10V		4		nC
Q _{gd}	Gate-Drain Charge			7		nC
DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS						
V _{SD}	Diode Forward Voltage	V _{GS} =0V, I _S =4A		0.81	1.2	V

Notes

- a.Surface Mounted on FR4 Board,t < 10sec.
- b.Pulse Test:Pulse Width < 300us, Duty Cycle < 2%.
- c.Guaranteed by design, not subject to production testing.
- d.Starting T_J=25°C,L=0.5mH,V_{DD} = 30V.(See Figure13)
- e.Drain current limited by maximum junction temperature.

STT626

Ver 1.0

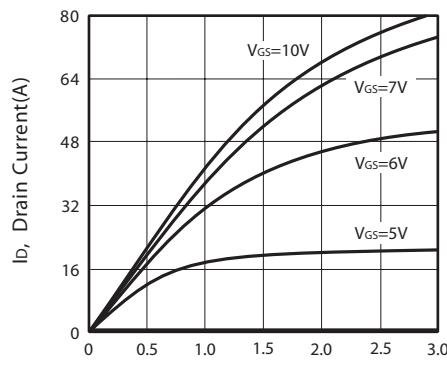


Figure 1. Output Characteristics

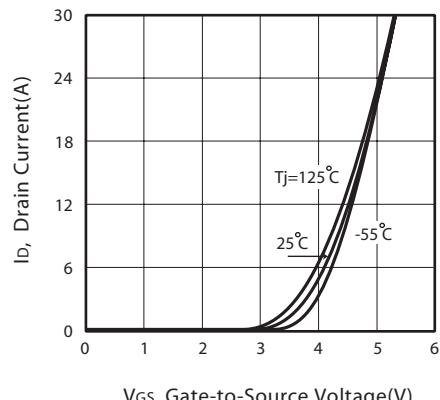


Figure 2. Transfer Characteristics

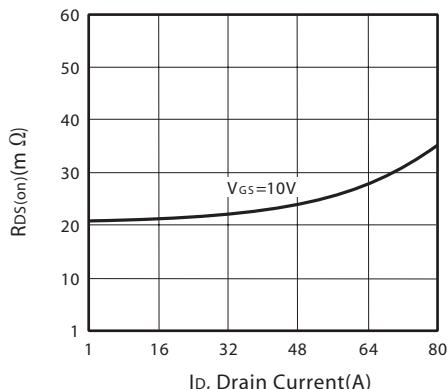


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

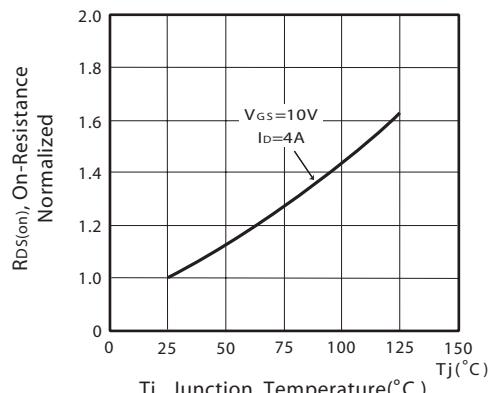


Figure 4. On-Resistance Variation with Drain Current and Temperature

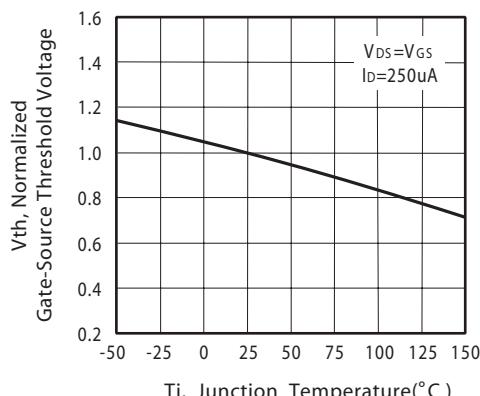


Figure 5. Gate Threshold Variation with Temperature

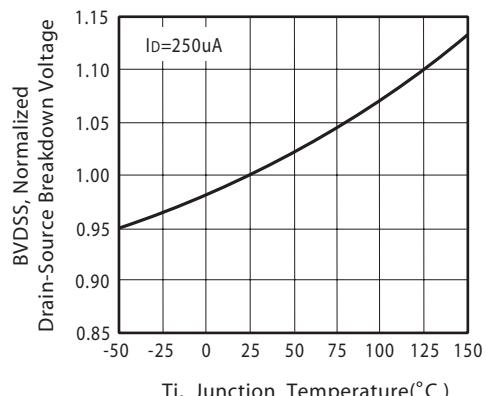
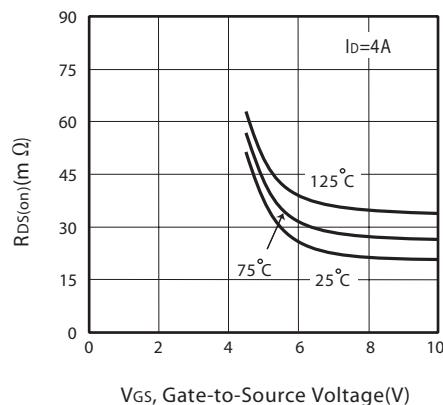


Figure 6. Breakdown Voltage Variation with Temperature

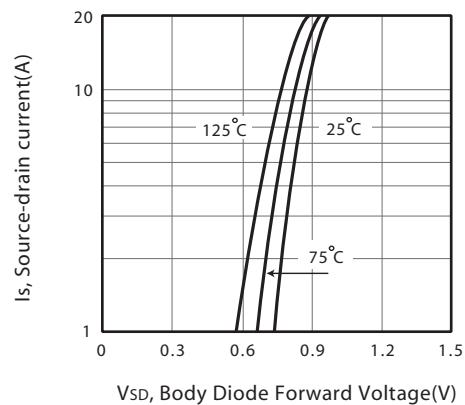
STT626

Ver 1.0



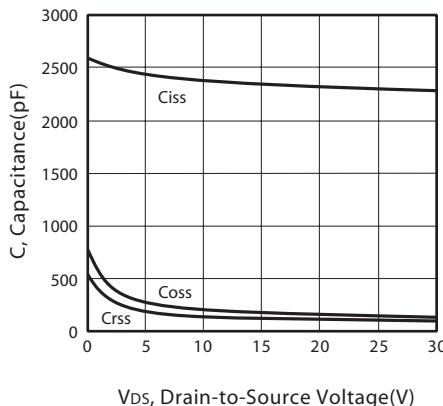
V_{GS}, Gate-to-Source Voltage(V)

Figure 7. On-Resistance vs. Gate-Source Voltage



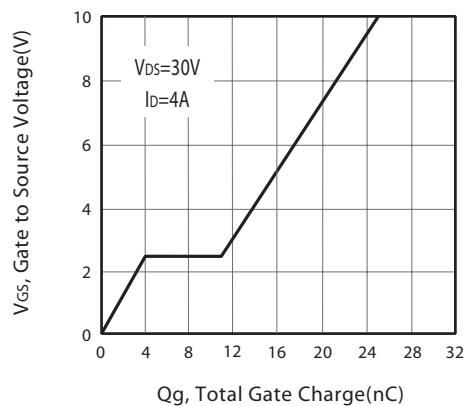
V_{SD}, Body Diode Forward Voltage(V)

Figure 8. Body Diode Forward Voltage Variation with Source Current



V_{DS}, Drain-to-Source Voltage(V)

Figure 9. Capacitance



Q_g, Total Gate Charge(nC)

Figure 10. Gate Charge

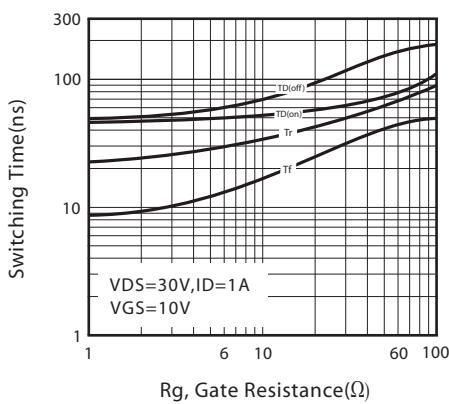


Figure 11. switching characteristics

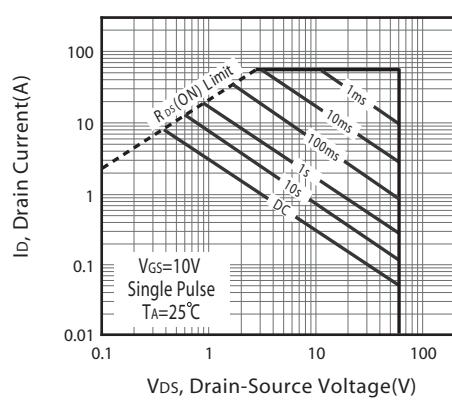
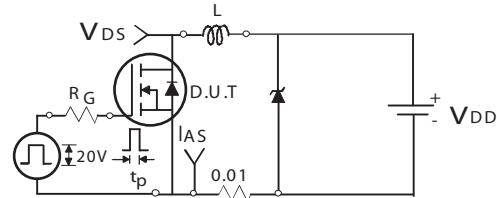
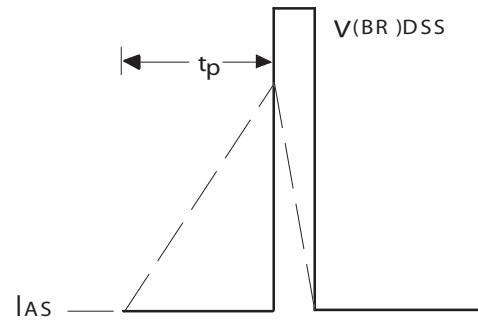


Figure 12. Maximum Safe Operating Area



Unclamped Inductive Test Circuit

Figure 13a.



Unclamped Inductive Waveforms

Figure 13b.

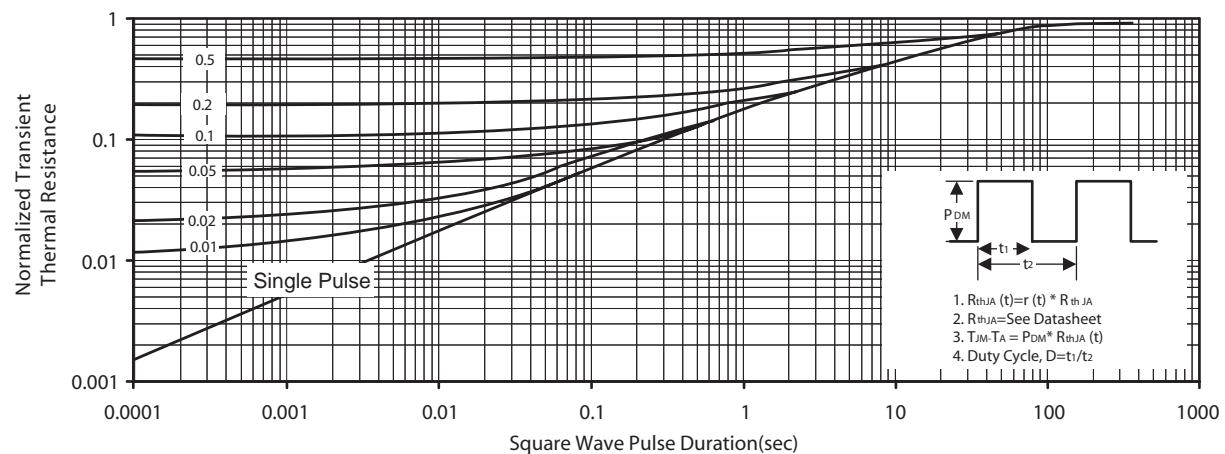
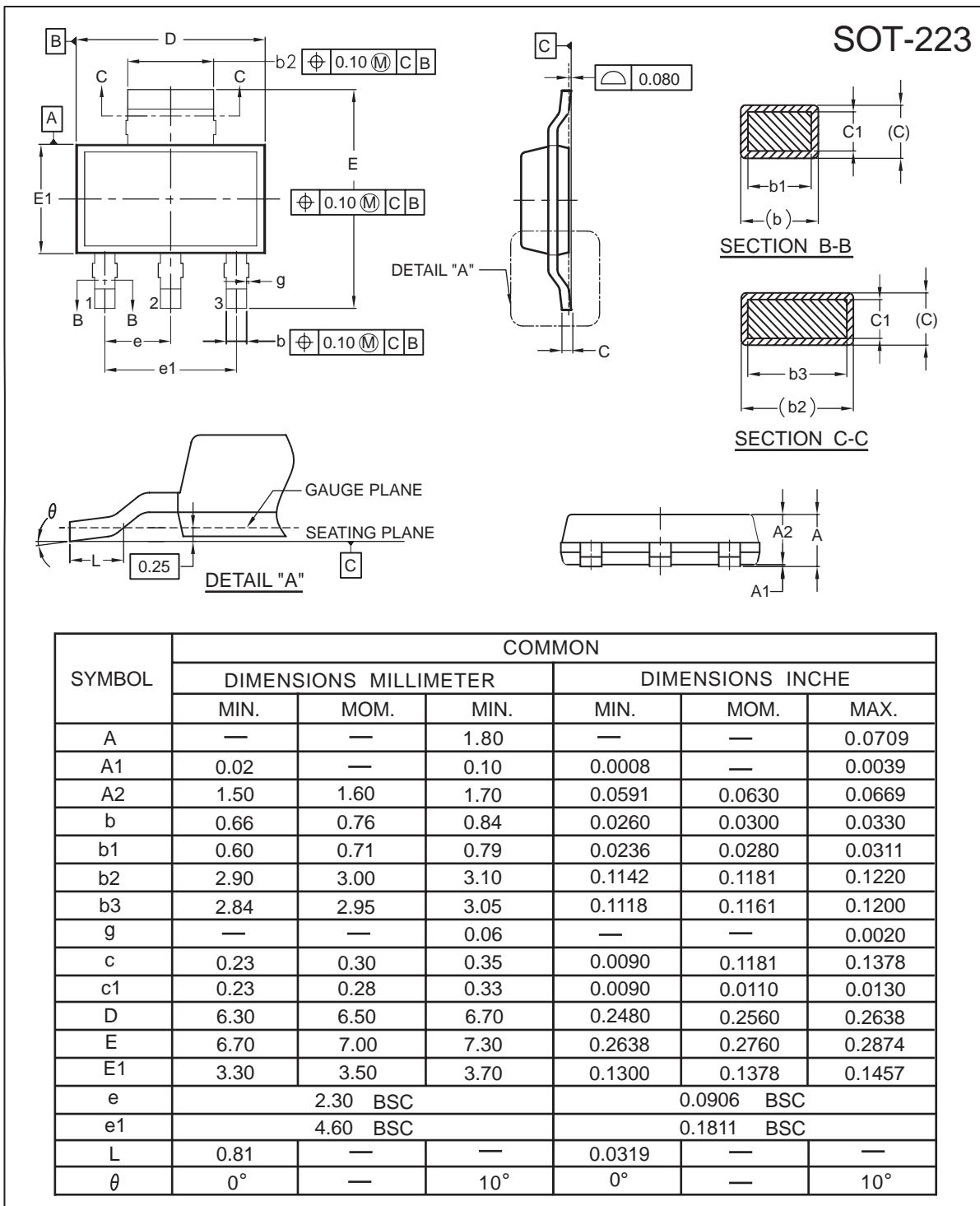


Figure 14. Normalized Thermal Transient Impedance Curve

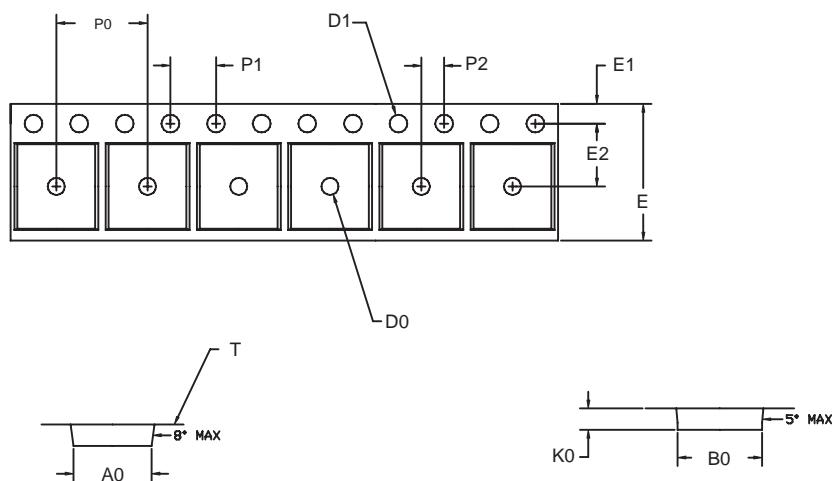
STT626

Ver 1.0



SOT-223 Tape and Reel Data

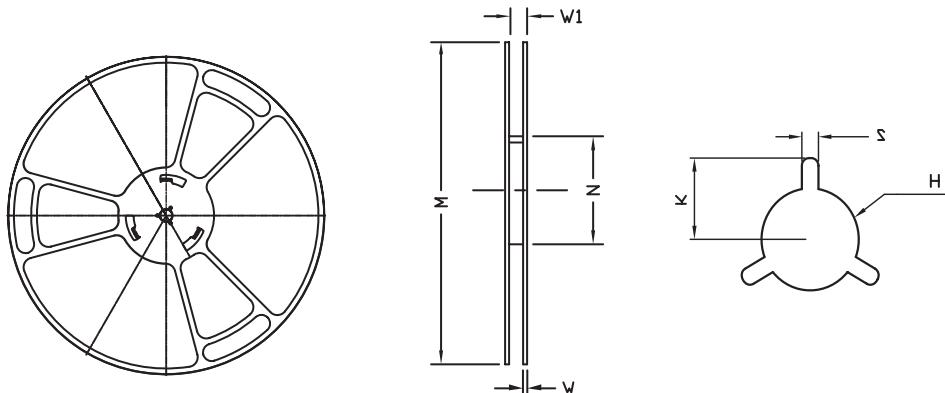
SOT-223 Carrier Tape



unit:mm

PACKAGE	A0	B0	K0	D0	D1	E	E1	E2	P0	P1	P2	T
---	6.83 ±0.1	7.42 ±0.1	1.88 ±0.1	1.50 + 0.25	1.60 + 0.1	12.0 + 0.3 - 0.1	1.75 ±0.1	5.50 ±0.5	8.0 ±0.1	4.00 ±0.1	2.00 ±0.05	0.292 ±0.02

SOT-223 Reel



UNIT:mm

REEL SIZE	M	N	W	W1	H	K	S	G	R	V
φ 330 ± 0.5	---	φ 97.0 ± 1.0	2.2	13.0 + 1.5	φ 13.0 + 0.5 - 0.2	10.6	2.0 ± 0.5	---	---	---

TOP MARKING DEFINITION

SOT-223

